

HD74HCT245

Octal Bus Transceivers (with 3-state outputs)

REJ03D0665-0200
(Previous ADE-205-554)
Rev.2.00
Mar 30, 2006

Description

This device has an active low enable input $\overline{G}$ and a direction control input (DIR). When DIR is high, data flows from the A inputs to the B outputs. When DIR is low, data flows from the B inputs to the A outputs. The HD74HCT245 transfers true data from one bus to the other.

This device does not have schmitt trigger inputs.

Features

- LSTTL Output Logic Level Compatibility as well as CMOS Output Compatibility
- High Speed Operation: t_{pd} (A to Y) = 12 ns typ ($C_L = 50$ pF)
- High Output Current: Fanout of 15 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 4.5$ to 5.5 V
- Low Input Current: 1 μ A max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max ($T_a = 25^\circ\text{C}$)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC245P	DILP-20 pin	PRDP0020AC-B (DP-20NEV)	P	—
HD74HC245FPEL	SOP-20 pin (JEITA)	PRSP0020DD-B (FP-20DAV)	FP	EL (2,000 pcs/reel)
HD74HC245RPEL	SOP-20 pin (JEDEC)	PRSP0020DC-A (FP-20DBV)	RP	EL (1,000 pcs/reel)
HD74HC245TELL	TSSOP-20 pin	PTSP0020JB-A (TTP-20DAV)	T	ELL (2,000 pcs/reel)

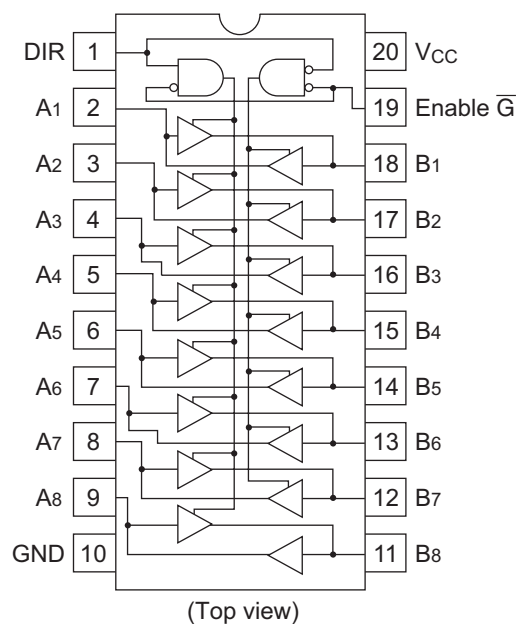
Note: Please consult the sales office for the above package availability.

Function Table

Enable $\overline{G}$	Direction Control DIR	Operation
L	L	B data to A bus
L	H	A data to B bus
H	X	Isolation

H : high level
L : low level
X : irrelevant

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
Input / Output voltage	V_{IN}, V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input / Output diode current	I_{IK}, I_{OK}	± 20	mA
Output current	I_O	± 35	mA
V_{CC} , GND current	I_{CC} or I_{GND}	± 75	mA
Power dissipation	P_T	500	mW
Storage temperature	T_{stg}	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	4.5 to 5.5	V	
Input / Output voltage	V_{IN}, V_{OUT}	0 to V_{CC}	V	
Operating temperature	T_a	-40 to 85	°C	
Input rise / fall time ^{*1}	t_r, t_f	0 to 500	ns	$V_{CC} = 4.5$ V

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

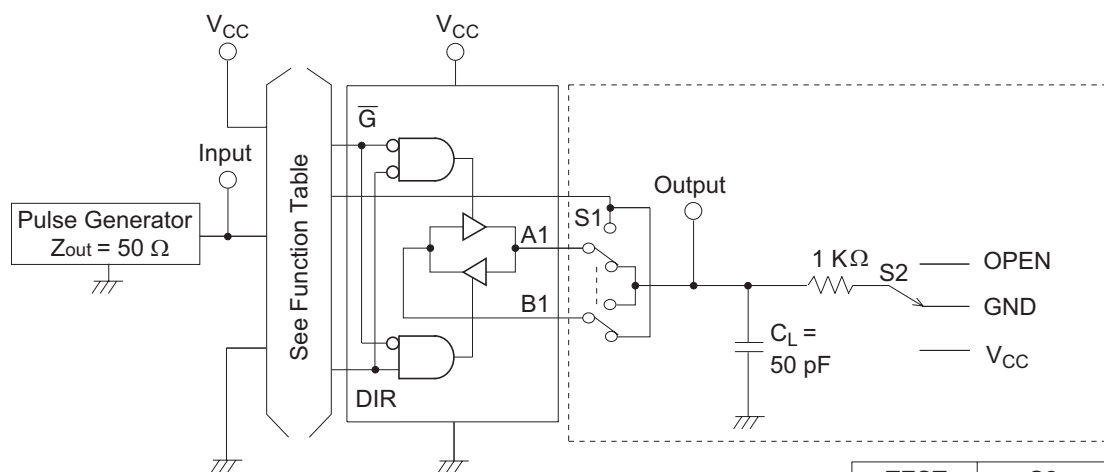
Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to+85°C		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Input voltage	V _{IH}	4.5 to 5.5	2.0	—	—	2.0	—	V		
	V _{IL}	4.5 to 5.5	—	—	0.8	—	0.8	V		
Output voltage	V _{OH}	4.5	4.4	—	—	4.4	—	V	Vin = V _{IH} or V _{IL}	I _{OH} = -20 μA
		4.5	4.18	—	—	4.13	—			I _{OH} = -6 mA
	V _{OL}	4.5	—	—	0.1	—	0.1	V	Vin = V _{IH} or V _{IL}	I _{OL} = 20 μA
		4.5	—	—	0.26	—	0.33			I _{OL} = 6 mA
Off-state output current	I _{OZ}	5.5	—	—	±0.5	—	±5.0	μA	Vin = V _{IH} or V _{IL} , Vout = V _{CC} or GND	
Input current	I _{in}	5.5	—	—	±0.1	—	±1.0	μA	Vin = V _{CC} or GND	
Quiescent current	I _{CC}	5.5	—	—	4.0	—	40	μA	Vin = V _{CC} or GND, Iout = 0 μA	

Switching Characteristics

($C_L = 50$ pF, Input $t_r = t_f = 6$ ns)

Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions
			Min	Typ	Max	Min	Max		
Propagation delay time	t _{PLH}	4.5	—	11	22	—	28	ns	
	t _{PHL}	4.5	—	13	22	—	28		
Output enable time	t _{ZL}	4.5	—	17	30	—	38	ns	
	t _{ZH}	4.5	—	14	30	—	38		
Output disable time	t _{LZ}	4.5	—	20	30	—	38	ns	
	t _{HZ}	4.5	—	22	30	—	38		
Output rise/fall time	t _{TLH} t _{THL}	4.5	—	4	12	—	15	ns	
Input capacitance	C _{in}	—	—	5	10	—	10	pF	

Test Circuit

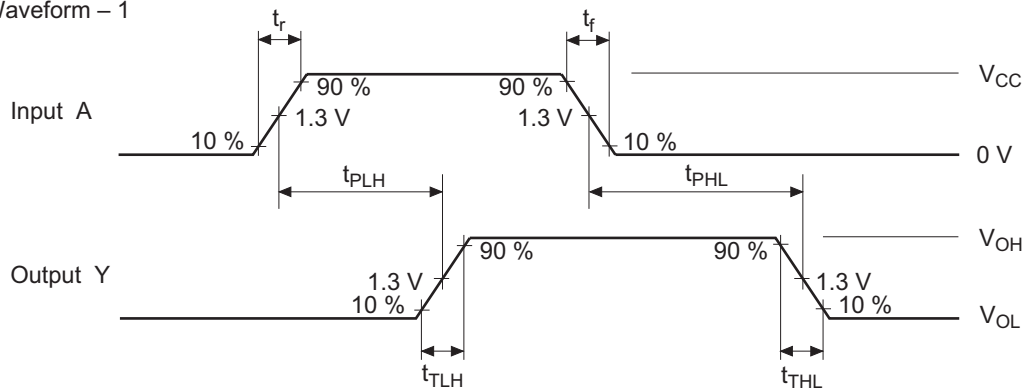


TEST	S2
t_{PLH} / t_{PHL}	OPEN
t_{ZH} / t_{HZ}	GND
t_{ZL} / t_{LZ}	V_{CC}

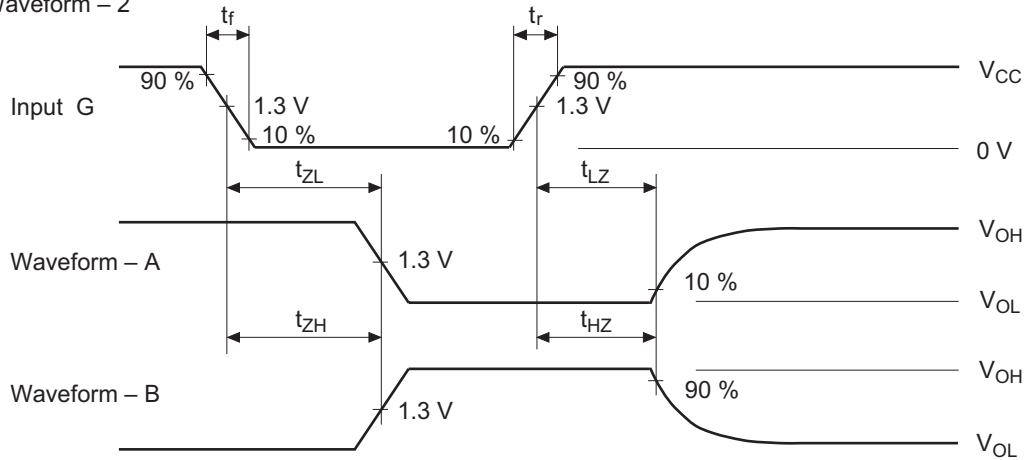
- Note : 1. C_L includes probe and jig capacitance.
2. A2-B2, A3-B3, A4-B4, A5-B5, A6-B6, A7-B7, A8-B8 are identical to above load circuit.
3. S1 is a input / output switch.

Waveforms

• Waveform – 1

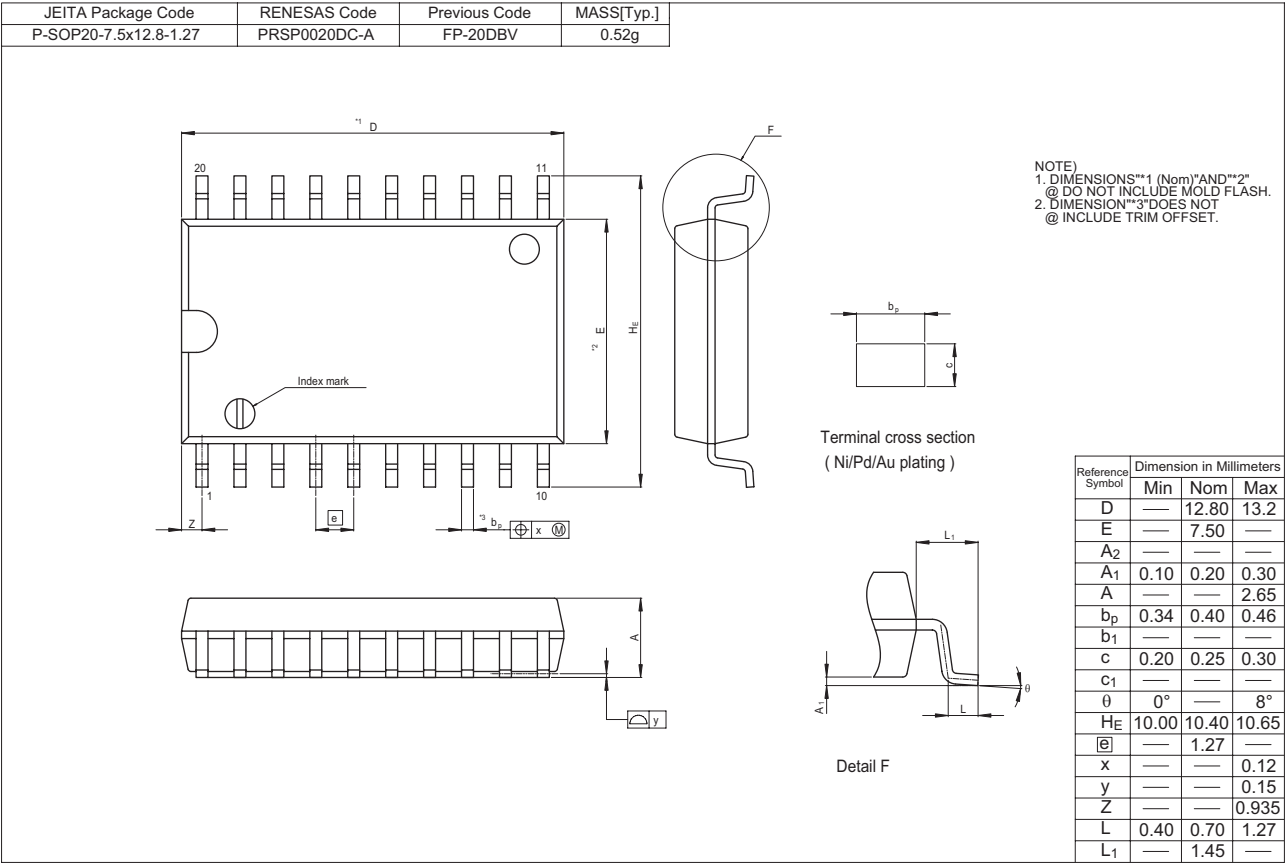
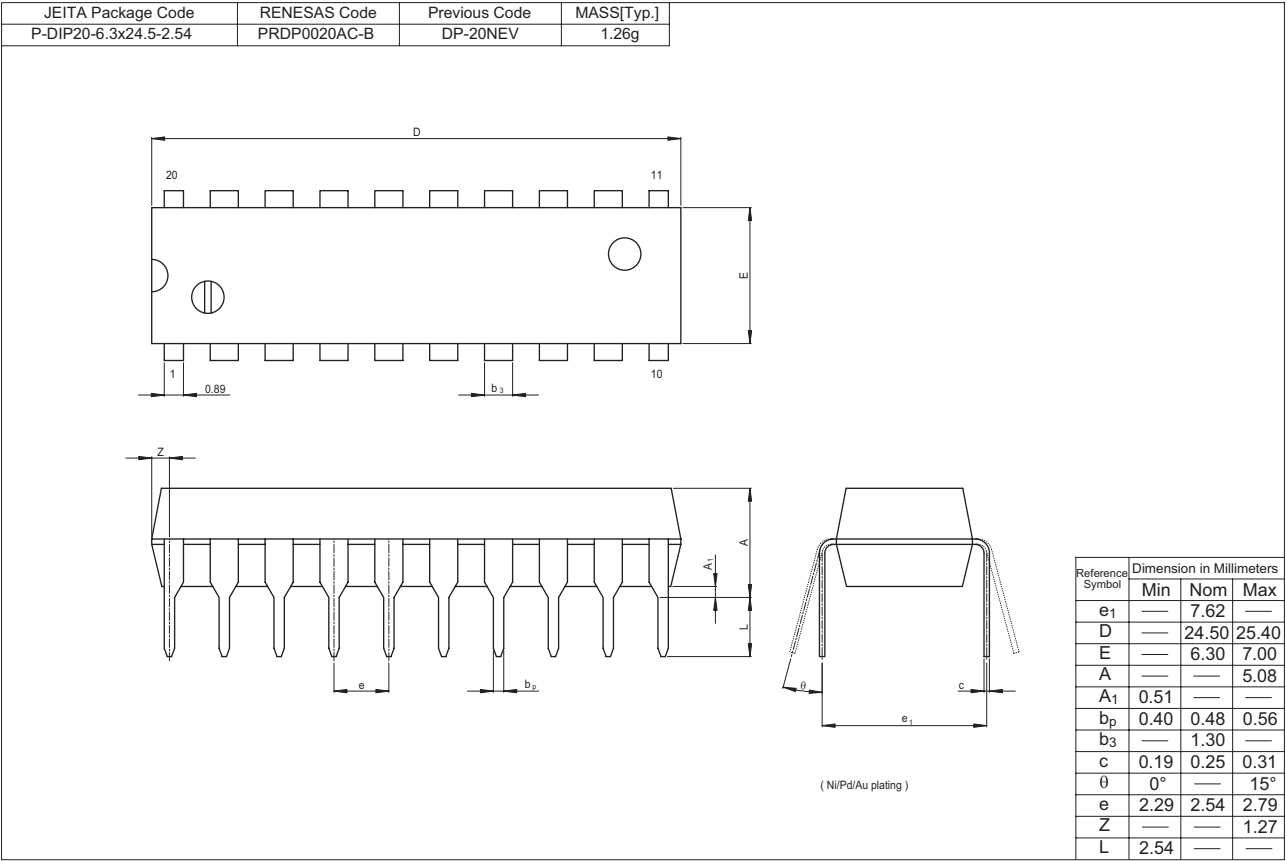


• Waveform – 2



- Notes :
1. Input waveform : $PRR \leq 1 \text{ MHz}$, duty cycle 50%, $t_r \leq 6 \text{ ns}$, $t_f \leq 6 \text{ ns}$
 2. Waveform– A is for an output with internal conditions such that the output is low except when disabled by the output control.
 3. Waveform– B is for an output with internal conditions such that the output is high except when disabled by the output control.
 4. The output are measured one at a time with one transition per measurement.

Package Dimensions



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